

SOT23 NPN SILICON PLANAR SMALL SIGNAL TRANSISTORS

FMMT5209 FMMT5210

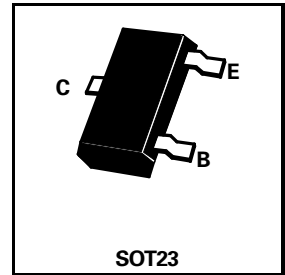
ISSUE 2 - JULY 1995



PARTMARKING DETAILS:

FMMT5209 - 2Q

FMMT5210 - 2R



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | FMMT5209 | FMMT5210 | UNIT |
|---|----------------|----------|-------------|------|
| Collector-Base Voltage | V_{CBO} | | 50 | V |
| Collector-Emitter Voltage | V_{CEO} | | 50 | V |
| Emitter-Base Voltage | V_{EBO} | | 4.5 | V |
| Continuous Collector Current | I_C | | 50 | mA |
| Power Dissipation | P_{tot} | | 330 | mW |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | | -55 TO +150 | °C |

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

| PARAMETER | SYMBOL | FMMT5209 | | FMMT5210 | | UNIT | CONDITIONS. |
|---------------------------------------|---------------|----------|------|----------|------|------|--|
| | | MIN. | MAX. | MIN. | MAX. | | |
| Collector-Base Cut-Off Current | I_{CBO} | | 50 | | 50 | nA | $V_{CB}=35\text{V}, I_E=0$ |
| Emitter-Base Cut-Off Current | I_{EBO} | | 50 | | 50 | nA | $V_{EB}=3\text{V}, I_C=0$ |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | | 700 | | 700 | mV | $I_C=10\text{mA}, I_B=1\text{mA}$ |
| Base-Emitter ON Voltage | $V_{BE(on)}$ | | 850 | | 850 | mV | $I_C=1\text{mA}, V_{CE}=5\text{V}$ |
| Static Forward Current Transfer Ratio | h_{FE} | 100 | 300 | 200 | 600 | | $I_C=100\mu\text{A}, V_{CE}=5\text{V}$ |
| | | 150 | | 250 | | | $I_C=1\text{mA}, V_{CE}=5\text{V}$ |
| | | 150 | | 250 | | | $I_C=10\text{mA}, V_{CE}=5\text{V}^*$ |
| Transition Frequency | f_T | 30 | | 30 | | MHz | $I_C=0.5\text{mA}, V_{CE}=5\text{V}, f=20\text{MHz}$ |
| Small Signal Current Transfer Ratio | h_{fe} | 150 | 600 | 250 | 900 | MHz | $I_C=1\text{mA}, V_{CE}=5\text{V}, f=1\text{KHz}$ |
| Noise Figure | N | 3 | | 2 | | dB | $I_C=200\mu\text{A}, V_{CE}=5\text{V}, R_g=2\text{K}\Omega, f=30\text{Hz to }15\text{KHz at }-3\text{dB points}$ |
| | | 4 | | 3 | | dB | $I_C=200\mu\text{A}, V_{CE}=5\text{V}, R_g=2\text{K}\Omega, f=1\text{KHz to } \Delta f=200\text{Hz}$ |
| Output Capacitance | C_{obo} | | 4 | | 4 | pF | $V_{CB}=5\text{V}, I_E=0, f=140\text{KHz}$ |